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12-Channel 1:2 MUX/DEMUX with 1.8V Compatible Control and Power-Down Mode

Check for Samples: TS3DV642

FEATURES

- Switch Type: 2:1 or 1:2
- Differential Bandwidth (–3dB)
 - Port A 6.9 GHz Typical
 - Port B 7.5 GHz Typical
- Ron
 - Port A 6.5 Ω Typical
 - Port B 8.2 Ω Typical
- Con: 4 pF Typ
- V_{CC} Range, 2.6 V–4.5 V
- I/O Voltage range, 0 V-5 V
- Special Features
 - I_{OFF} Protection Prevents Current Leakage in Powered Down State (V_{CC} = 0 V)
- ESD Performance
 - 2 kV Human Body Model (A114B, Class II)
 - 1 kV Charged Device Model (C101)
- 42-pin QFN Package (9 x 3.5 mm, 0.5 mm Pitch)

APPLICATIONS

- HDMI 1.4/DVI 1.0 Signal Switching
- DisplayPort 1.2 Signal Switching
- General Purpose TMDS Signal Switching
- General Purpose LVDS Signal Switching
- General Purpose High Speed Signal Switching

DESCRIPTION

The TS3DV642 is a 12 channels 1:2 or 2:1 bidirectional multiplexer/demultiplexer. The TS3DV642 operates from a 2.6 to 4.5 V supply, making it suitable for battery-powered applications. It offers low and flat ON-state resistance as well as low I/O capacitance which allow it to achieve a typical bandwidth of up to 7.5 GHz. The device provides the high bandwidth necessary for HDMI and DisplayPort applications.

The TS3DV642 offers a power-down mode, in which all channels become high-Z and the device operates with minimal power.

TYPICAL APPLICATION DIAGRAM

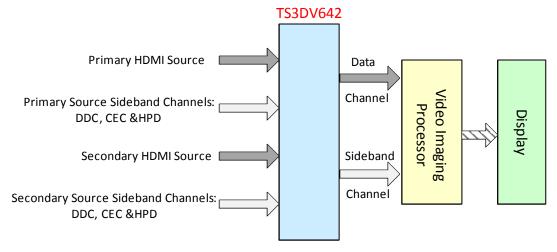


Figure 1. Typical 2:1 HDMI Demux Application

ORDERING INFORMATION

T _A	PA	CKAGE	ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 85°C	QFN – RUA	Tape and Reel	TS3DV642RUAR	SD642A0



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PIN DESCRIPTION

	PIN DESCRIPTION									
					P	IN	I/O Type	DESCRIPTION		
					NAME	NUMBER	i/O Type	DESCRIPTION		
		<			VCC	1	Power	Supply Voltage		
		SCL_SDA_SCL_SCL_SCL_			GND	PowerPad	GND	Ground		
		SCL_SCL_SCL_SCL_SCL_SCL_SCL_SCL_SCL_SCL_			SEL1	16	I	Select Input 1		
					SEL2	17	I	Select Input 2		
		(42) (41) (40) (33)			EN	2	I	Output Enable		
VCC	1	Ll	38	D0+A	D0+A	38	I/O	Port A, Lane 0, +ve signal		
EN	2	1	(37	D0-A	D0-A	37	I/O	Port A, Lane 0, -ve signal		
SCL	3	! !	<u>36</u>	D1+A	D1+A	36	I/O	Port A, Lane 1, +ve signal		
		! !			D1-A	35	I/O	Port A, Lane 1, -ve signal		
SDA	4		<u>35</u>	D1-A	D2+A	34	I/O	Port A, Lane 2, +ve signal		
D0+	5		34	D2+A	D2–A	33	I/O	Port A, Lane 2,-ve signal		
		! !			D3+A	32	I/O	Port A, Lane 3, +ve signal		
D0-	6	i	(33	D2-A	D3–A	31	I/O	Port A, Lane 3, -ve signal		
D1+	7	i i	(32	D3+A	SCL_A	42	I/O	Port A, DDC Clock		
D1-	8	i i	(31	D3-A	SDA_A	41	I/O	Port A, DDC Data		
		i our i			HPD_A	19	1/0	Port A, Hot Plug Detects		
NC	9	i GND i	(30	NC	CEC_A	18	I/O	Port A, Consumer Electronics Control		
D2+	10)	1	(29	D0+B	D0+B	29	I/O	Port B, Lane 0, +ve signal		
		1			D0-B	28	1/0	Port B, Lane 0, –ve signal		
D2-	11)	! !	(28	D0-B	D1+B	27	1/0	Port B, Lane 1, +ve signal		
D3+	12)		(27	D1+B	D1-B	26	1/0	Port B, Lane 1, –ve signal		
D3-	13)		(26	D1-B	D2+B	25	1/0	Port B, Lane 2, +ve signal		
				-	D2-B	24	1/0	Port B, Lane 2,—ve signal		
HPD	14)	1	(25	D2+B	D3+B	23	1/0	Port B, Lane 3, +ve signal		
CEC	<u>15</u>)	i	24	D2-B	D3-B	22	1/0	Port B, DDC Clock		
SEL1	<u>16</u>)	i i	(23	D3+B	SCL_B	40 39	I/O I/O	Port B, DDC Clock Port B, DDC Data		
		i i			SDA_B HPD_B	21	1/0	Port B, Hot Plug Detects		
SEL2	<u>17</u>)		(22	D3-B	CEC_B	20	1/0	Port B, Consumer Electronics Control		
		21 29 13 18			D0+	5	I/O	Common Port, Lane 0, +ve signal		
		⋖. ∢. ฌ. ฌ .			D0-	6	I/O	Common Port, Lane 0, -ve signal		
					D1+	7	I/O	Common Port, Lane 1, +ve signal		
		CEC_ HPD_ CEC_ HPD_			D1-	8	I/O	Common Port, Lane 1, -ve signal		
		0 – 0 –			D2+	10	I/O	Common Port, Lane 2, +ve signal		
					D2-	11	I/O	Common Port, Lane 2, -ve signal		
					D3+	12	I/O	Common Port, Lane 3, +ve signal		
					D3-	13	I/O	Common Port, Lane 3,-ve signal		
					SCL	3	I/O	Common Port, DDC Clock		
					SDA	4	I/O	Common Port, DDC Data		
				-	HPD	14	I/O	Common Port, Hot Plug Detects		
					CEC	15	I/O	Common Port, Consumer Electronics Control		
					NC	9, 30	NC	No Connect		



LOGIC DIAGRAM

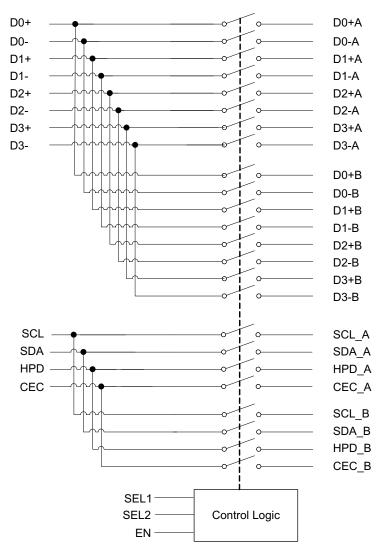


Table 1. Functional Table

EN	SEL1	SEL2	FUNCTION
L	Χ	Х	Switch Disabled. All Channel Hi-Z.
Н	L	L	D0+/D0- to D0+A/D0-A ON. All the other channels Hi-Z.
Н	L	Н	D0+/D0- to D0+B/D0-B ON. All the other channels Hi-Z.
Н	Н	L	Channel A Enabled. Channel B Hi-Z.
Н	Н	Н	Channel B Enabled. Channel A Hi-Z.



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ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	5.5	V
V _{I/O}	Analog voltage range (2)(3)(4)	All I/O	-0.5	5.5	V
V _{IN}	Digital input voltage range (2)(3)	SEL1, SEL2,EN	-0.5	5.5	V
I _{I/OK}	Analog port diode current	V _{I/O} < 0		-50	mA
I _{IK}	Digital input clamp current	V _{IN} < 0		-50	mA
I _{I/O}	On-state switch current (5)		-128	128	mA
θ_{JA}	Package thermal impedance (6)	RUA package		TBD	°C/W
T _{stg}	Storage temperature range		-65	150	°C

- Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings (1) only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- All voltages are with respect to ground, unless otherwise specified.
- The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- V_I and V_O are used to denote specific conditions for V_{I/O}.
- (5) I_I and I_O are used to denote specific conditions for I_{I/O}.
- The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS(1)

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V_{CC}	Supply voltage	2.6	4.5	V
$V_{I/O}$	Input/Output voltage	0	5.5	V
T _A	Operating free-air temperature	-40	85	°C

All unused control inputs of the device must be held at VDD or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

ELECTRICAL CHARACTERISTICS

	PARAMETER		TEST CONDITIONS ⁽¹⁾	MIN TYP ⁽²⁾	MAX	UNIT
PORT A						
D	ON-state resistance	D0 to D3	$V_{CC} = 3 \text{ V}, 1.5 \text{ V} \le V_{I/O} \le V_{CC},$	6.5	9.5	Ω
R _{ON}	ON-State resistance	SCL, SDA, HPE, CEC	$I_{I/O} = -40 \text{ mA}$	6	9.5	Ω
R _{ON(flat)} (3)	ON-state resistance flatness	All I/O	$V_{CC}=3$ V, $V_{I/O}=1.5$ V and $V_{CC},$ $I_{I/O}=-40$ mA	1.5		Ω
ΔR _{ON} ⁽⁴⁾	On-state resistance match between high-speed channels	D0 to D3	$\label{eq:VCC} \begin{aligned} &\text{VCC} = 3 \text{ V, 1.5 V} \leq \text{VI/O} \leq \text{V}_{\text{CC}}, \\ &\text{I}_{\text{I/O}} = -40 \text{ mA} \end{aligned}$	0.4	1	Ω
I _{OFF}	Leakage under power off	All outputs			±10	μΑ
PORT B						
D	ON-state resistance	D0 to D3	$V_{CC} = 3 \text{ V}, 1.5 \text{ V} \le V_{I/O} \le V_{CC},$	8.2	10.5	Ω
R _{ON}	ON-state resistance	SCL, SDA, HPE, CEC	II/O = -40 mA	6	10.5	Ω
R _{ON(flat)} (3)	ON-state resistance flatness	All I/O	V_{CC} = 3 V, $V_{I/O}$ = 1.5 V and V_{CC} , $I_{I/O}$ = -40 mA	1.5		Ω
ΔR _{ON} ⁽⁴⁾	On-state resistance match between high-speed channels	D0 to D3	$V_{CC} = 3 \text{ V}, 1.5 \text{ V} \le V_{I/O} \le V_{CC},$ $I_{I/O} = -40 \text{ mA}$	0.4	1	Ω
I _{OFF}	Leakage under power off	All outputs	$V_{CC} = 0 \text{ V}, V_{I/O} = 0 \text{ V to } 3.6 \text{ V}, V_{IN} = \text{V to } 5.5 \text{ V}$		±10	μΑ

- V_I , V_O , I_I , and I_O refer to I/O pins, V_{IN} refers to the control inputs All typical values are at V_{CC} = 3.3V (unless otherwise noted), T_A = 25°C
- R_{ON(FLAT)} is the difference of R_{ON} in a given channel at specified voltages.
- ΔR_{ON} is the difference of RON from center port to any other ports. (4)

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ELECTRICAL CHARACTERISTICS (continued)

	PARAMETER	₹	TEST CONDITIONS ⁽¹⁾	MIN	TYP ⁽²⁾	MAX	UNIT
DIGITAL I	NPUTS (SEL1, SEL2, EN)		•				
V _{IH}	High-level control input voltage	SEL1, SEL2, EN		1.4		3.6	V
V _{IL}	Low-level control input voltage	SEL1, SEL2, EN		0		0.5	V
I _{IH}	Digital input high leakage current	SEL1, SEL2, EN	$V_{CC} = 3.6 \text{ V}$, $V_{IN} = V_{DD}$			±10	μΑ
I _{IL}	Digital input low leakage current	SEL1, SEL2, EN	V _{CC} = 3.6 V, V _{IN} = GND			±10	μΑ
SUPPLY							
I _{CC}	VCC supply current		$V_{CC} = 3.6 \text{ V}, I_{I/O} = 0, \text{ Normal Operation}$ Mode, EN = H		50		μΑ
I _{CC} , PD	VCC supply current in por	wer-down mode	$V_{CC} = 3.6 \text{ V}, I_{I/O} = 0, EN = L$		6		μA

SWITCHING CHARACTERISTICS

over recommended operation free-air temperature range, V_{CC} = 3.3 V± 0.3 V (unless otherwise noted)

	PARAME	TER		TEST CONDITIONS	MIN TYP(1)	MAX	UNIT	
t _{ON} (2)	Switch turn-on time		All I/O	See Figure 2		100	μs	
t _{SWITCH} (3)	Switching time betwe	witching time between channels		See Figure 3	20		μs	
			D0 to D3		30			
t _{pd}	Propagation Delay	Port A	SCL, SDA, HPD, CEC		30			
			D0 to D3	See Figure 4	40		ps	
		Port B	SCL, SDA, HPD, CEC		30			
	latan nain Cleans	Port A			2			
	Inter-pair Skew	Port B	D0 to D0		2			
t _{SKEW}	lates a sin Cleans	Port A	D0 to D3		2		ps	
	Intra-pair Skew	Port B			6			

- (1) All typical values are at $V_{CC} = 3.3 \text{ V}$ (unless otherwise noted), $T_A = 25 ^{\circ}\text{C}$. (2) t_{ON} is the time it takes the output to recover after enabling switches t_{SWITCH} is the time it takes for the output to recover after the state is changed

DYNAMIC CHARACTERISTICS

Over recommended operation free-air temperature range, $V_{CC} = 3.3V \pm 0.3V$ (unless otherwise noted)

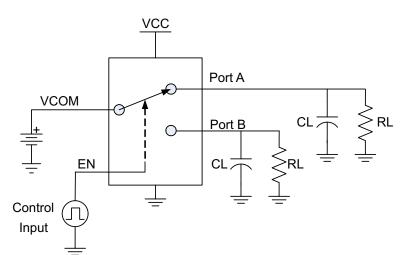
	PARAMETER		TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT		
C _{IN}	Digital input capacitand	е	f = 1 MHz, V _{IN} = 0 V		6		pF		
Coff	Switch OFF capacitano	е	$f = 1 \text{ GHz}$, $V_{I/O} = 0 \text{ V}$, Output is open, Switch is OFF		0.3		pF		
Con	on Switch ON capacitance		f = 1 GHz, V _{I/O} = 0 V, Output is open, Switch is ON		0.5		рF		
Xtalk Differential Crosstalk			$R_L = 50 \Omega$ at 1.7 GHz (See Figure 5)		-40		dB		
Alaik	Ataik Differential Crosstalk		$R_L = 50 \Omega$ at 2.7 GHz (See Figure 6)		-40		ив		
OISO	0100 577 - 6 1071 1 6		$R_L = 50 \Omega$ at 1.7 GHz (See Figure 6)				٩D		
0130	Differential Off Isolation	1	$R_L = 50 \Omega$ at 2.7 GHz (See Figure 6)		-28		dB		
IL	Insertion Loss		Port A at DC		-0.75		dB		
IL	insertion Loss		Port B at DC		-1		dB		
BW	Differential Bandwidth	Port A	$R_L = 50 \Omega$, All channels (See Figure 7)		6.9		GHz		
DVV	(-3 dB)	Port B	$R_L = 50 \Omega$, All channels (See Figure 7)		7.5		GHZ		

(1) All Typical Values are at V_{CC} = 3.3V (unless otherwise noted), T_A = 25°C.

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PARAMETER MEASUREMENT INFORMATION



RL	CL	Vсом
50Ω	4pF	Vcc

*CL includes probe, cable, and board capacitance

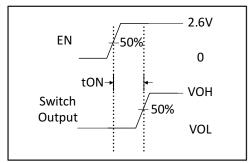
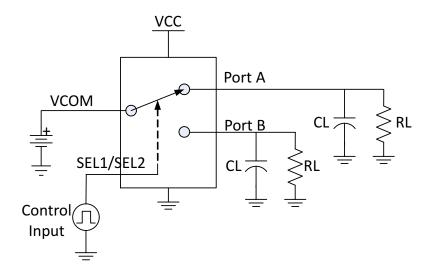


Figure 2. Switch Turn-On Time (ton)



RL	CL	Vсом
50Ω	4pF	Vcc

*CL includes probe, cable, and board capacitance

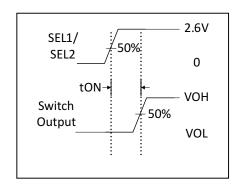
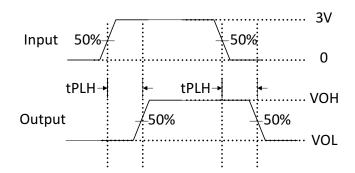


Figure 3. Switching Time Between Channels (t_{SWITCH})



tpd = (tPLH + tPLH)/2

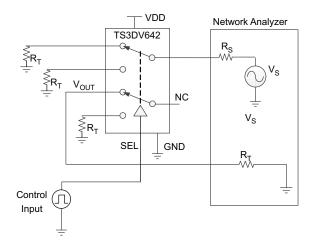
Figure 4. Propagation Delay (tpd)

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PARAMETER MEASUREMENT INFORMATION (continued)



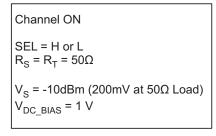
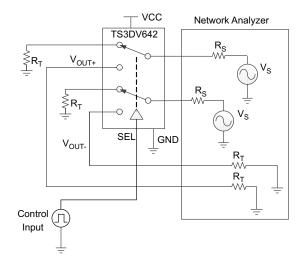
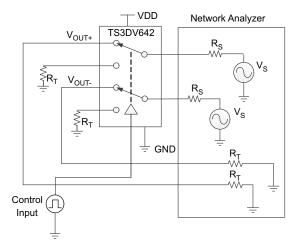


Figure 5. Crosstalk (Xtalk)



```
Channel OFF SEL = H \text{ or } L R_S = R_T = 50\Omega V_S = -10 dBm (200 mV \text{ at } 50\Omega \text{ Load}) V_{DC\_BIAS} = 1 \text{ V}
```

Figure 6. Differential Off-Isolation (OISO)



```
Channel ON SEL = H \text{ or } L R_S = R_T = 50\Omega V_S = -10 \text{dBm (200mV at } 50\Omega \text{ Load)} V_{DC\_BIAS} = 1 \text{ V}
```

Figure 7. Differential Bandwidth (BW)

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TEXAS INSTRUMENTS

TYPICAL CHARACTERISTICS

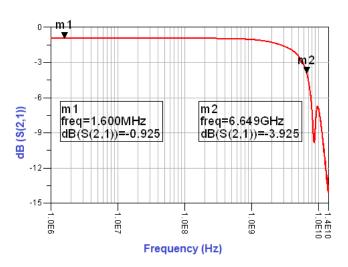


Figure 8. Differential S21 vs Frequency for Port A

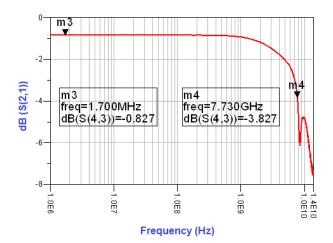


Figure 9. Differential S21 vs Frequency for Port B

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TYPICAL CHARACTERISTICS (continued)

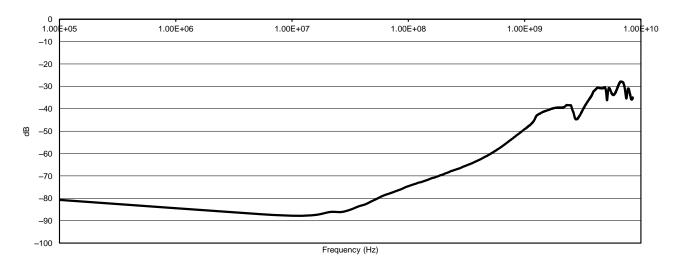


Figure 10. XTALK Port A

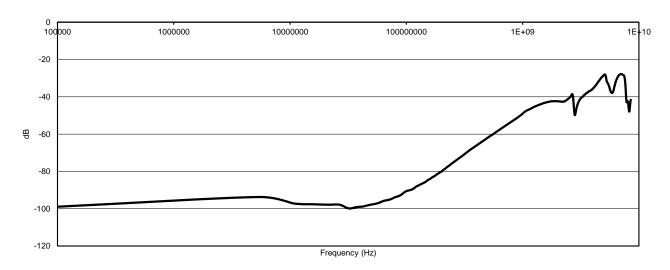


Figure 11. XTALK Port B

TYPICAL CHARACTERISTICS (continued)

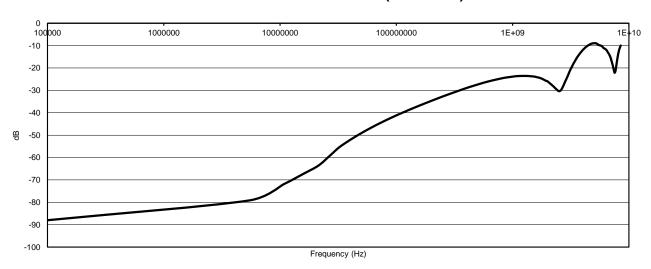


Figure 12. OIRR Port A

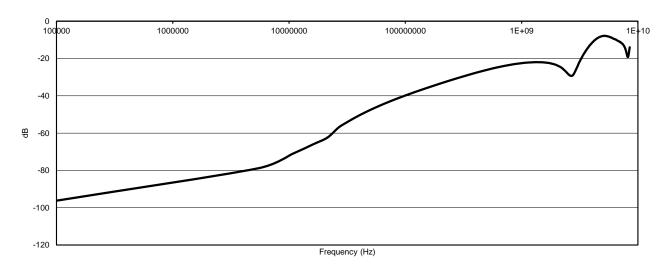


Figure 13. OIRR Port B

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PACKAGE OPTION ADDENDUM

2-Jun-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Diawing		Q.	(2)		(3)		(4/5)	
TS3DV642A0RUAR	ACTIVE	WQFN	RUA	42	3000	Green (RoHS	CU NIPDAU	Level-2-260C-1 YEAR		SD642A0	Samples
						& no Sb/Br)					Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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PACKAGE MATERIALS INFORMATION

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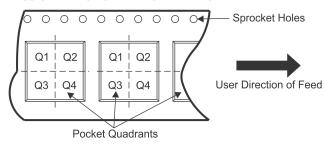
TAPE AND REEL INFORMATION





		Dimension designed to accommodate the component width
E	30	Dimension designed to accommodate the component length
K	(0	Dimension designed to accommodate the component thickness
	N	Overall width of the carrier tape
F	21	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS3DV642A0RUAR	WQFN	RUA	42	3000	330.0	16.4	3.8	9.3	1.0	8.0	16.0	Q1

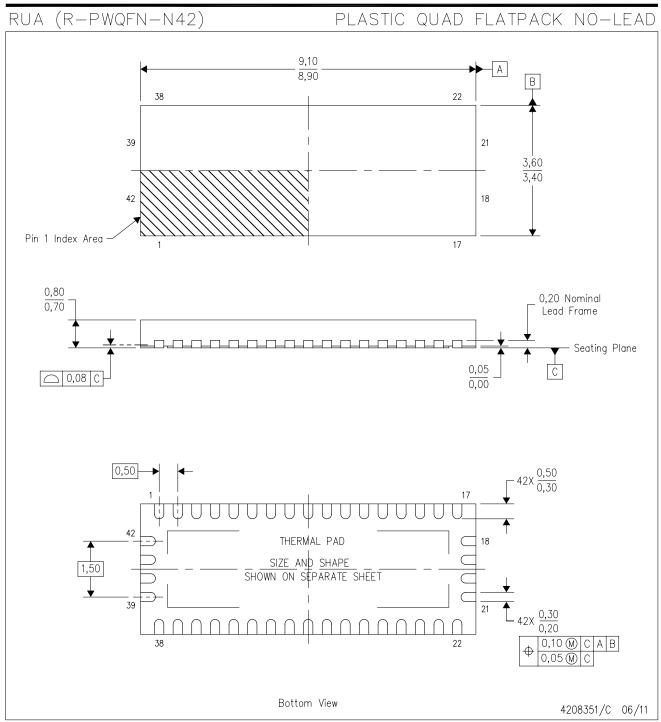
PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
TS3DV642A0RUAR	WQFN	RUA	42	3000	367.0	367.0	38.0	



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.



RUA (R-PWQFN-N42)

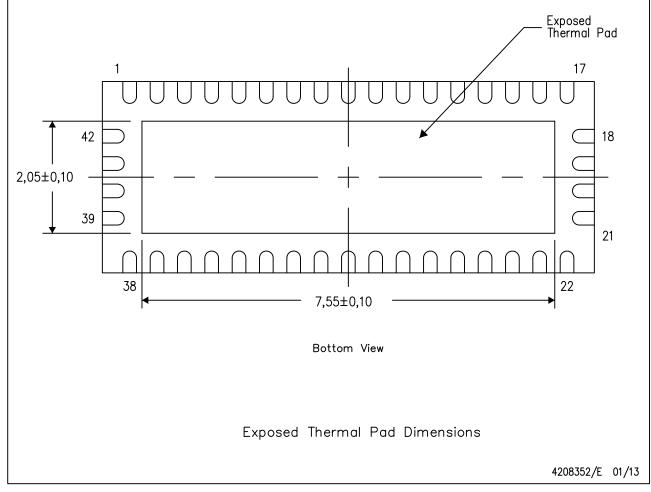
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

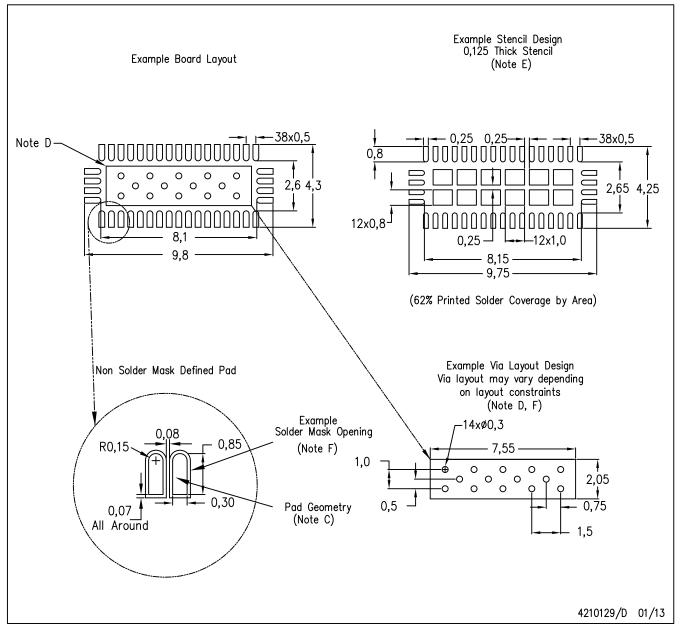


NOTE: All linear dimensions are in millimeters



RUA (R-PWQFN-N42)

PLASTIC QUAD FLATPACK NO-LEAD



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.



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